NSN 5961-01-372-1070

Yes - demil/mli

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Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-372-1070 **Inclosure Material:** Metal **Overall Length:** Between 0.124 inches and 0.134 inches **Terminal Length:** Between 0.492 inches and 0.571 inches **Overall Diameter:** Between 0.354 inches and 0.362 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case and quality assurance level tx **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 0.285 limiting voltage **Current Rating Per Characteristic:** 30.00 nanoamperes forward current, average peak **Power Rating Per Characteristic:** 325.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 80.0 degrees celsius junction **Test Data Document:** 95105-995-9501 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**